

## **SSC8033GS6A**

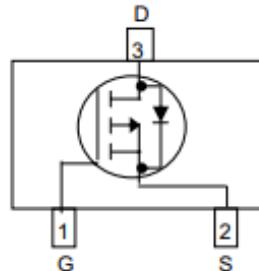
### **P-Channel Enhancement Mode MOSFET**

#### ➤ Features

VDS	VGS	RDS(on) Typ.	ID
-30V	$\pm 20V$	45mR@-10V	-4.5A
		62mR@-4V5	

#### ➤ Pin configuration

Top view

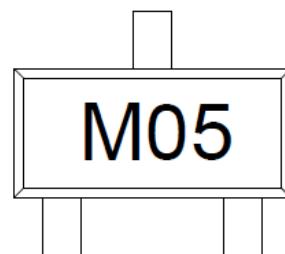


#### ➤ Description

This P-Channel enhancement mode power FETs are produced with high cell density, DMOS trench technology, which is especially used to minimize on-state resistance. This device is particularly suited for low voltage application such as portable equipment, power management and other battery powered circuits and low in-line power loss are needed in a very small outline surface mount package.



SOT23-3L



Marking

#### ➤ Applications

- TFT panel power switch
- High side DC/DC Converter
- High side driver for brushless DC motor
- Portable DVD, DPF

#### ➤ Ordering Information

Device	Package	Shipping
SSC8033GS6A	SOT23-3	3000/Reel

➤ **Absolute Maximum Ratings( $T_A=25^\circ\text{C}$  unless otherwise noted)**

Symbol	Parameter	Ratings	Unit
$V_{DSS}$	Drain-to-Source Voltage	-30	V
$V_{GSS}$	Gate-to-Source Voltage	$\pm 20$	V
$I_D$	Continuous Drain Current <sup>a</sup>	-4.5	A
$I_{DM}$	Pulsed Drain Current <sup>b</sup>	-16	A
$P_D$	Power Dissipation <sup>c</sup>	1.5	W
$P_{DSM}$	Power Dissipation <sup>a</sup>	0.85	W
$T_J$	Operation junction temperature	-55 to 150	$^\circ\text{C}$
$T_{STG}$	Storage temperature range	-55 to 150	$^\circ\text{C}$

➤ **Thermal Resistance Ratings( $T_A=25^\circ\text{C}$  unless otherwise noted)**

Symbol	Parameter	Typical	Maximum	Unit
$R_{\theta JA}$	Junction-to-Ambient Thermal Resistance <sup>a</sup>		150	$^\circ\text{C/W}$
$R_{\theta JC}$	Junction-to-Case Thermal Resistance		85	

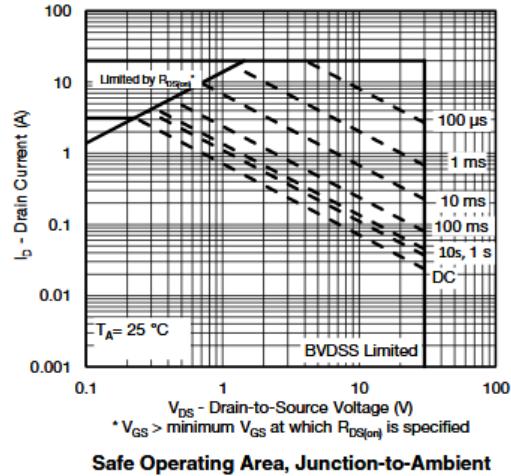
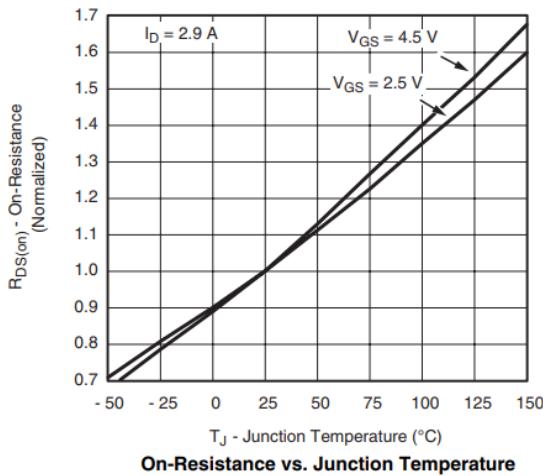
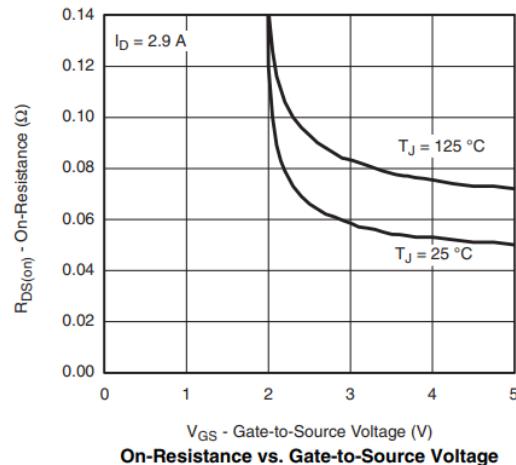
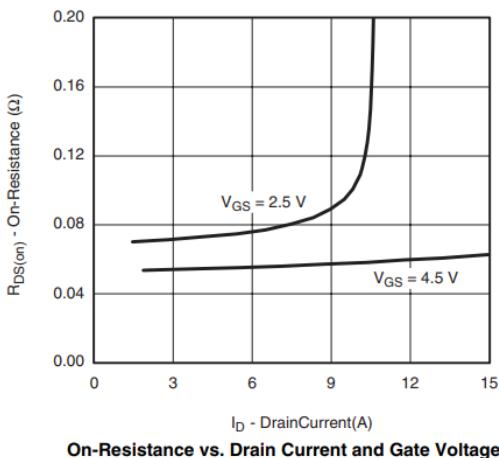
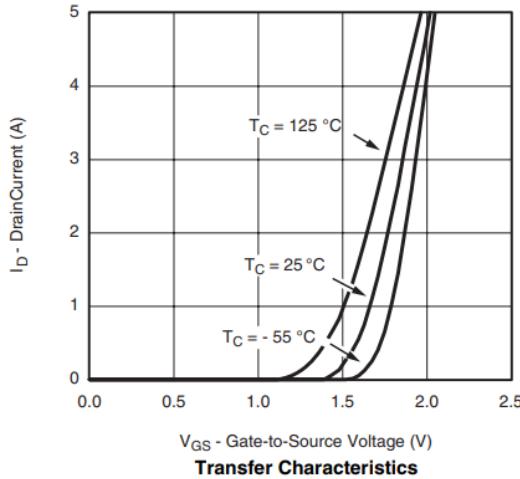
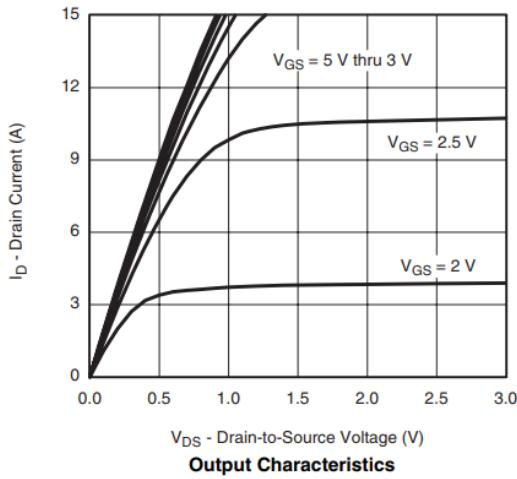
Note:

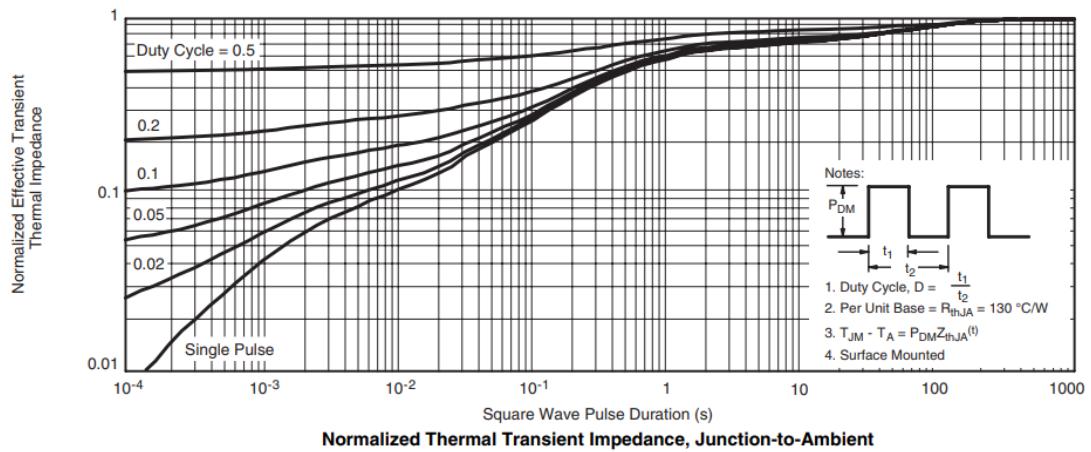
- a. The value of  $R_{\theta JA}$  is measured with the device mounted on 1 in<sup>2</sup> FR-4 board with 2oz.copper,in a still air environment with  $T_A=25^\circ\text{C}$ .The value in any given application depends on the user specific board design. The current rating is based on the  $t \leq 10\text{s}$  thermal resistance rating.
- b. Repetitive rating, pulse width limited by junction temperature.
- c. The power dissipation  $P_D$  is based on  $T_{J(MAX)}=150^\circ\text{C}$ , using junction-to-case thermal resistance, and is more useful in setting the upper dissipation limit for cases where additional heat sinking is used.

➤ Electronics Characteristics( $T_A=25^\circ C$  unless otherwise noted)

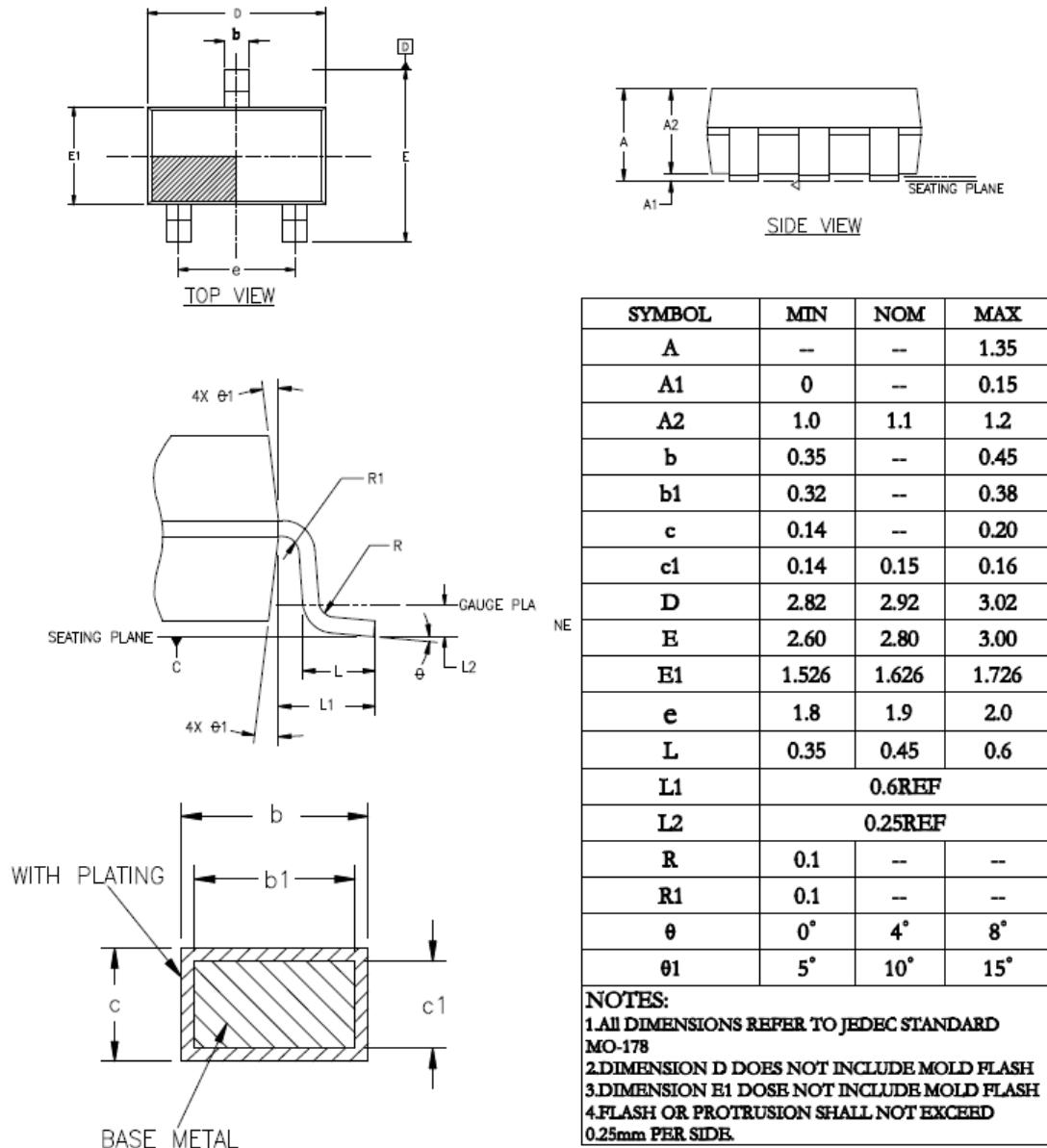
Symbol	Parameter	Test Conditions	Min	Typ.	Max	Unit
$V_{(BR)DSS}$	Drain-Source Breakdown Voltage	$V_{GS}=0V, ID=-250\mu A$	-30			V
$V_{GS(\text{th})}$	Gate Threshold Voltage	$V_{DS}=V_{GS}, ID=-250\mu A$	-1	-1.5	-2	V
$R_{DS(on)}$	Drain-Source On-Resistance	$V_{GS}=-10V, ID=-4.1A$		45	70	mR
		$V_{GS}=-4.5V, ID=-3A$		62	90	
$I_{DSS}$	Zero Gate Voltage Drain Current	$V_{DS}=-30V, V_{GS}=0V$			-1	$\mu A$
$I_{GSS}$	Gate-Source leak current	$V_{GS}=\pm 20V, V_{DS}=0V$			$\pm 100$	nA
$G_{FS}$	Transconductance	$V_{DS}=-5V, ID=-2.8A$		6		S
$V_{SD}$	Forward Voltage	$V_{GS}=0V, IS=-0.75A$		-0.8	-1.3	V
$C_{iss}$	Input Capacitance	$V_{DS}=-6V, V_{GS}=0V, F=1MHz$		680		pF
$C_{oss}$	Output Capacitance			72		
$C_{rss}$	Reverse Transfer Capacitance			58		
$T_{D(ON)}$	Turn-on delay time	$V_{GEN}=-4.5V, V_{DS}=-6V, RL=6R, RG=6R, ID=-1A$		20		ns
$Tr$	Rise time			14		
$T_{D(OFF)}$	Turn-off delay time			65		
$T_f$	Fall time			21		

➤ **Typical Characteristics( $T_A=25^\circ\text{C}$  unless otherwise noted)**





➤ Package Information



**SOT23-3L**



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